1. DESCRIPTION

The XD14069 hex inverter is constructed with MOS P−channel and N−channel enhancement mode devices in a single monolithic structure. These inverters find primary use where low power dissipation and/or high noise immunity is desired. Each of the six inverters is a single stage to minimize propagation delays.

2. FEATURES

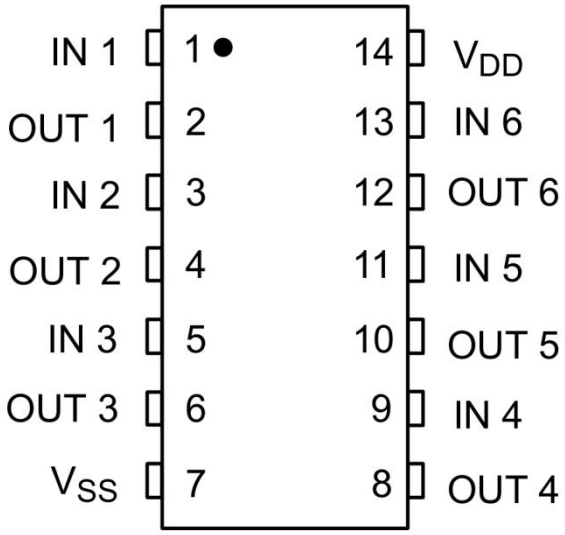
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low−Power TTL Loads or One Low−Power Schottky TTL Load Over the Rated Temperature Range
- Triple Diode Protection on All Inputs
- Meets JEDEC UB Specifications

3. MAXIMUMRATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	−0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage Range (DC or Transient)	−0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P_D	Power Dissipation, per Package (Note 1)	500	mW
T_A	Ambient Temperature Range	−40to +85	°C
T_{stg}	Storage Temperature Range	−65 to +150	°C
T_L	Lead Temperature (8−Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

4. PIN ASSIGNMENT



(Top View)

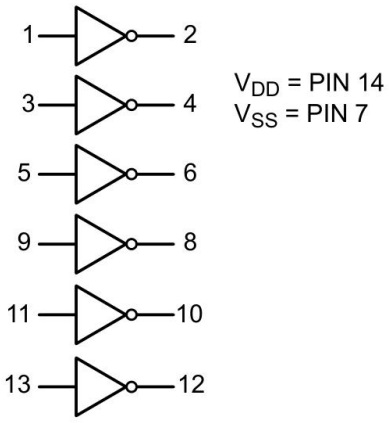
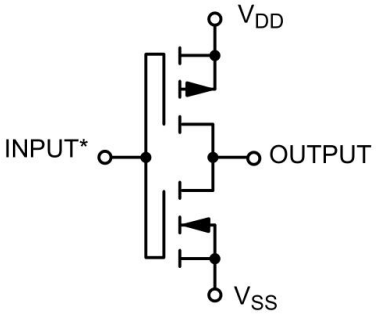


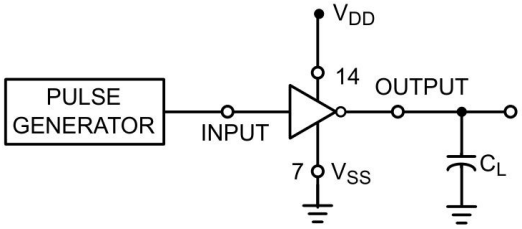
Figure 1. Logic Diagram



*Double diode protection on all inputs not shown

(1/6 of circuit shown)

Figure 2. Circuit Schematic



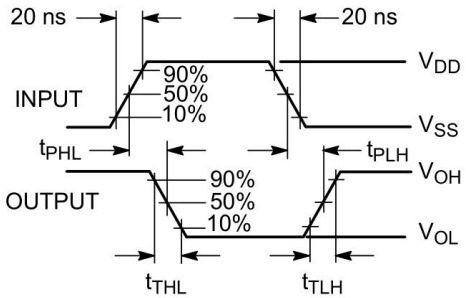


Figure 3. Switching Time Test Circuit and Waveforms

5. ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	-40°C		25°C			85°C		Unit
			Min	Max	Min	Typ (Note 2)	Max	Min	Max	
Output Voltage "0" Level V_{in} = V_{DD}	V_{OL}	5.0	–	0.05	–	0	0.05	–	0.05	Vdc
		10	–	0.05	–	0	0.05	–	0.05	
		15	–	0.05	–	0	0.05	–	0.05	
V_{in} = 0 "1" Level	V_{OH}	5.0	4.95	–	4.95	5.0	–	4.95	–	Vdc
		10	9.95	–	9.95	10	–	9.95	–	
		15	14.95	–	14.95	15	–	14.95	–	
Input Voltage "0" Level (V_O = 4.5 Vdc)	V_{IL}	5.0	–	1.0	–	2.25	1.0	–	1.0	Vdc
(V_O = 9.0 Vdc)		10	–	2.0	–	4.50	2.0	–	2.0	
(V_O = 13.5 Vdc)		15	–	2.5	–	6.75	2.5	–	2.5	
"1" Level (V_O = 0.5 Vdc)	V_{IH}	5.0	4.0	–	4.0	2.75	–	4.0	–	Vdc
(V_O = 1.0 Vdc)		10	8.0	–	8.0	5.50	–	8.0	–	
(V_O = 1.5 Vdc)		15	12.5	–	12.5	8.25	–	12.5	–	
Output Drive Current (V_{OH} = 2.5 Vdc) Source	I_{OH}	5.0	–3.0	–	–2.4	–4.2	–	–1.7	–	mAdc
(V_{OH} = 4.6 Vdc)		5.0	–0.64	–	–0.51	–0.88	–	–0.36	–	
(V_{OH} = 9.5 Vdc)		10	–1.6	–	–1.3	–2.25	–	–0.9	–	
(V_{OH} = 13.5 Vdc)		15	–4.2	–	–3.4	–8.8	–	–2.4	–	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.64	–	0.51	0.88	–	0.36	–	mAdc
(V_{OL} = 0.5 Vdc)		10	1.6	–	1.3	2.25	–	0.9	–	
(V_{OL} = 1.5 Vdc)		15	4.2	–	3.4	8.8	–	2.4	–	
Input Current	I_{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	µAdc
Input Capacitance (Vin = 0)	C_{in}	–	–	–	–	5.0	7.5	–	–	pF
Quiescent Current (Per Package)	I_{DD}	5.0	–	0.25	–	0.0005	0.25	–	7.5	µAdc
		10	–	0.5	–	0.0010	0.5	–	15	
		15	–	1.0	–	0.0015	1.0	–	30	

Total Supply Current (Notes 3 and 4) (Dynamic plus Quiescent, Per Gate) (C_L = 50 pF)	I_T	5.0 10 15	I_T = (0.3 µA/kHz) f + I_{DD}/6 I_T = (0.6 µA/kHz) f + I_{DD}/6 I_T = (0.9 µA/kHz) f + I_{DD}/6							µAdc
Output Rise and Fall Times (Note 3) (C_L = 50 pF) t_{TLH}, t_{THL} = (1.35 ns/pF) C_L + 33 ns t_{TLH}, t_{THL} = (0.60 ns/pF) C_L + 20 ns t_{TLH}, t_{THL} = (0.40 ns/pF) C_L + 20 ns	t_{TLH}, t_{THL}	5.0 10 15	– – –	– – –	– – –	100 50 40	200 100 80	– – –	– – –	ns
Propagation Delay Times (Note 3) (C_L = 50 pF) t_{PLH}, t_{PHL} = (0.90 ns/pF) C_L + 20 ns t_{PLH}, t_{PHL} = (0.36 ns/pF) C_L + 22 ns t_{PLH}, t_{PHL} = (0.26 ns/pF) C_L + 17 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	– – –	– – –	65 40 30	125 75 55	– – –	– – –	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

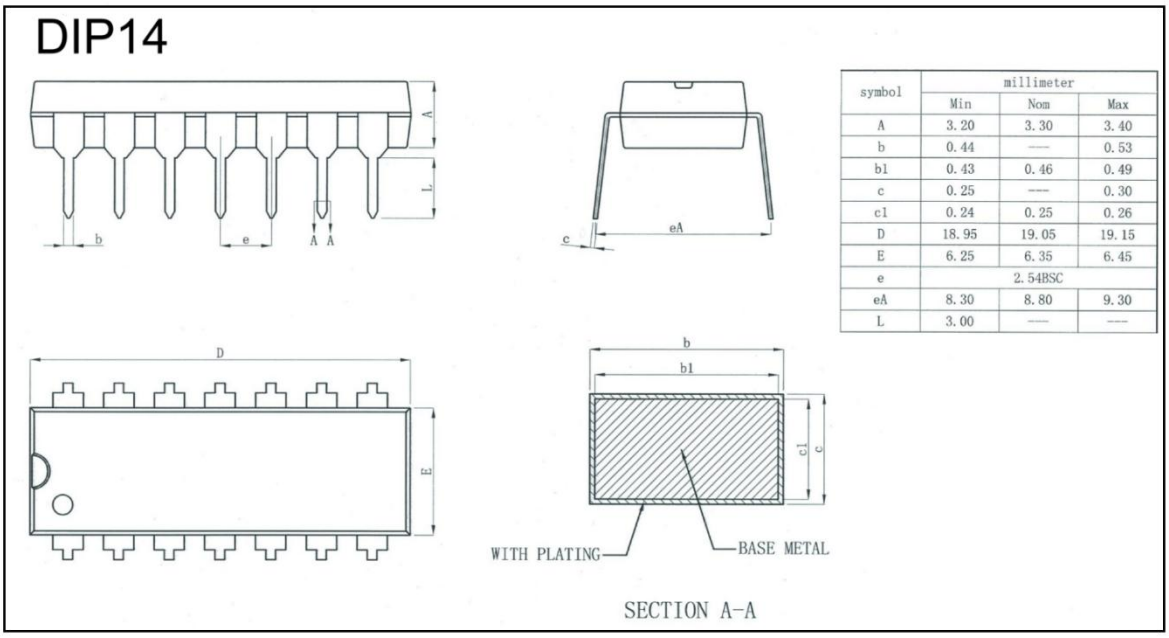
where: I_T is in µA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.002.

6. ORDERING INFORMATION

Ordering Information

Part Number	Device Marking	Package Type	Body size (mm)	Temperature (°C)	MSL	Transport Media	Package Quantity
XD14069	XD14069	DIP14	19.05 * 6.35	- 40 to 85	MSL3	Tube 25	1000

7. DIMENSIONAL DRAWINGS



symbol	millimeter		
	Min	Nom	Max
A	3.20	3.30	3.40
b	0.44	——	0.53
b1	0.43	0.46	0.49
c	0.25	——	0.30
c1	0.24	0.25	0.26
D	18.95	19.05	19.15
E	6.25	6.35	6.45
e		2.54BSC	
eA	8.30	8.80	9.30
L	3.00	——	——